

PMEG4002EB

0.2 A very low V_F MEGA Schottky barrier rectifier in SOD523 package

Rev. 02 — 13 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small and flat lead Surface Mounted Device (SMD) plastic package.

1.2 Features

Forward current: 200 mA

Reverse voltage: 40 V

- Very low forward voltage
- Ultra small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|-----------------|------------------------|--------------|-----|-----|------|
| IF | forward current | | - | - | 200 | mA |
| V _R | reverse voltage | | - | - | 40 | V |
| V _F | forward voltage | $I_F = 200 \text{ mA}$ | <u>[1]</u> - | 520 | 600 | mV |

[1] Pulse test: $t_0 \le 300 \ \mu s$; $\delta \le 0.02$.





2. Pinning information

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Table 2. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|--------------------|--------|
| 1 | cathode | [1] | |
| 2 | anode | 1 2 | 1 🔁 2 |
| | | | sym001 |

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PMEG4002EB | SC-79 | plastic surface mounted package; 2 leads | SOD523 |

4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMEG4002EB | L9 |

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|---|-----------------|------|------|
| V_{R} | reverse voltage | | - | 40 | V |
| I _F | forward current | | - | 200 | mA |
| I _{FRM} | repetitive peak forward current | $t_p \leq 1 \text{ s; } \delta \leq 0.5$ | - | 300 | mA |
| I _{FSM} | non-repetitive peak forward current | t_p = 8.3 ms half sine wave; JEDEC method | - | 1 | A |
| Tj | junction temperature | | - | 150 | °C |
| T_{amb} | ambient temperature | | - 65 | +150 | °C |
| T _{stg} | storage temperature | | - 65 | +150 | °C |

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------|---|-------------|--------|-----|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1][2] | - | - | 450 | K/W |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

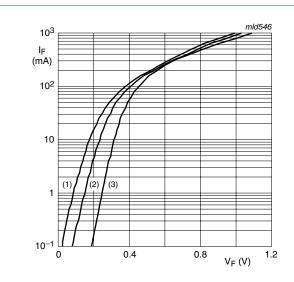
| | | • | | | | |
|----------------|----------------------|---------------------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _F | forward voltage | $I_F = 0.1 \text{ mA}$ | - | 190 | 220 | mV |
| | | I _F = 1 mA | - | 250 | 290 | mV |
| | | I _F = 10 mA | - | 320 | 360 | mV |
| | | I _F = 100 mA | - | 440 | 500 | mV |
| | | I _F = 200 mA | - | 520 | 600 | mV |
| I _R | reverse current | V _R = 25 V | <u>[1]</u> _ | - | 0.5 | μΑ |
| C_{d} | diode capacitance | $V_R = 1 V$; $f = 1 MHz$ | - | - | 20 | pF |

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating will be available on request.

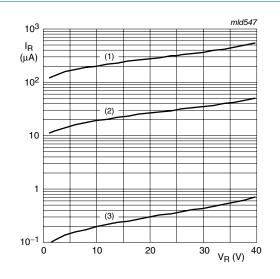
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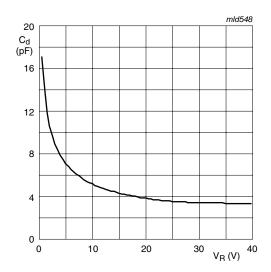
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) T_{amb} = 25 °C

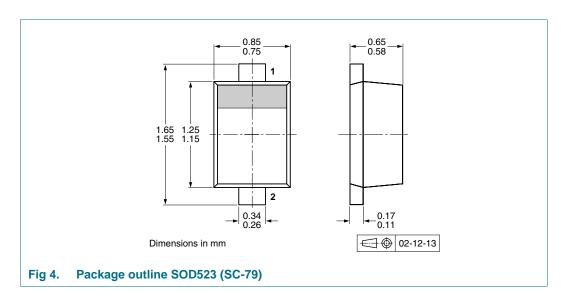
Fig 2. Reverse current as a function of reverse voltage; typical values



 T_{amb} = 25 °C; f = 1 MHz

Fig 3. Diode capacitance as a function of reverse voltage; typical values

8. Package outline



9. Packing information

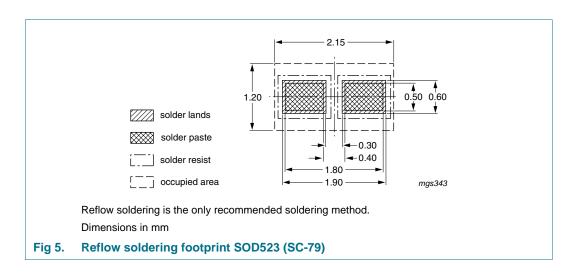
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing | quantity |
|-------------|---------|--------------------------------|---------|----------|
| | | | 3000 | 10000 |
| PMEG4002EB | SOD523 | 4 mm pitch, 8 mm tape and reel | -115 | -135 |

^[1] For further information and the availability of packing methods, see Section 13.

10. Soldering



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11. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|--------------------------------|---|-----------------------|--------------|--|--|
| PMEG4002EB_2 | 20100113 | Product data sheet | - | PMEG4002EB_1 | | |
| Modifications: | including ned content. | This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content. | | | | |
| | Figure 5 "Re | flow soldering footprint SO | D523 (SC-79)": update | ed | | |
| PMEG4002EB_1 | 20050712 | Product data sheet | - | - | | |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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